Amendments to the Claims:

This listing of claims will replace all prior versions, and listings, of claims in the application:

Listing of Claims:

Claim 1 (Currently Amended): A semiconductor light-emitting element comprising:

a substrate,

a first epitaxial layer group to emit a yellow color light provided on the substrate and made of II-VI semiconductor compounds, said first epitaxial layer group including an active layer, and

a second epitaxial layer group to emit a blue color light provided on the substrate and made of II-VI semiconductor compounds.

Claim 2 (Original): A semiconductor light-emitting element as defined in claim 1, wherein the first epitaxial layer group includes a light-emitting active layer made of a II-VI semiconductor compound containing Zn, Se, Te and Cd.

Claim 3 (Previouly Amended): A semiconductor light-emitting element as defined in claim 2, wherein the light-emitting active layer is made of a II-VI semiconductor compound having a composition of $Zn_{1-X}Cd_XSe_{1-Y}Te_Y$ ($0.1<X<0.4$, $0.1<Y<0.4$).

Claim 4 (Previously Amended): A semiconductor light-emitting element as defined in claim 2, wherein the first epitaxial layer group includes a first optical waveguide layer and a second optical waveguide layer which sandwich the light-emitting active layer and are made of II-VI semiconductor compounds containing Be and Mg, respectively.

Claim 5 (Previously Amended): A semiconductor light-emitting element as defined in claim 4, wherein the first epitaxial layer group includes a first cladding layer and a second cladding layer which sandwich the first optical waveguide layer and the second optical waveguide layer on the outside of the first and the second optical waveguide layers, and are made of II-VI semiconductor compounds containing Be and Mg, respectively.

Claim 6 (Original): A semiconductor light-emitting element as defined in claim 1, wherein the second epitaxial layer group includes a light-emitting active layer made of a II-VI semiconductor compound containing Zn, Se, Te and Cd.

Claim 7 (Original): A semiconductor light-emitting element as defined in claim 6, wherein the light-emitting active layer is made of a II-VI semiconductor compound having a composition of $Zn_{1-Z}Cd_ZSe_{1-V}Te_V$ ($0<Z<0.1$, $0<V<0.1$).

Claim 8 (Previously Amended): A semiconductor light-emitting element as defined in claim 6, wherein the second epitaxial layer group includes a first optical

waveguide layer and a second optical waveguide layer which sandwich the light-emitting active layer and are made of II-VI semiconductor compounds containing Be and Mg, respectively.

Claim 9 (Previously Amended): A semiconductor light-emitting element as defined in claim 8, wherein the second epitaxial layer group includes a first cladding layer and a second cladding layer which sandwich the first optical waveguide layer and the second optical waveguide layer on the outside of the first and the second optical waveguide layers, and are made of II-VI semiconductor compounds containing Be and Mg, respectively.